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New Horizons in Condensed Matter Physics
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Scanning Tunneling Spectroscopy Study of Cuprates and a Topological Superconductor

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Outline

- ✓ *Cross-Sectional STM Study of $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ and $\text{YBa}_2\text{Cu}_3\text{O}_{7-x}$*
- ✓ *Nematic (2-fold symmetric) field dependence of the superconducting gap of $\text{Cu}_x\text{Bi}_2\text{Se}_3$*

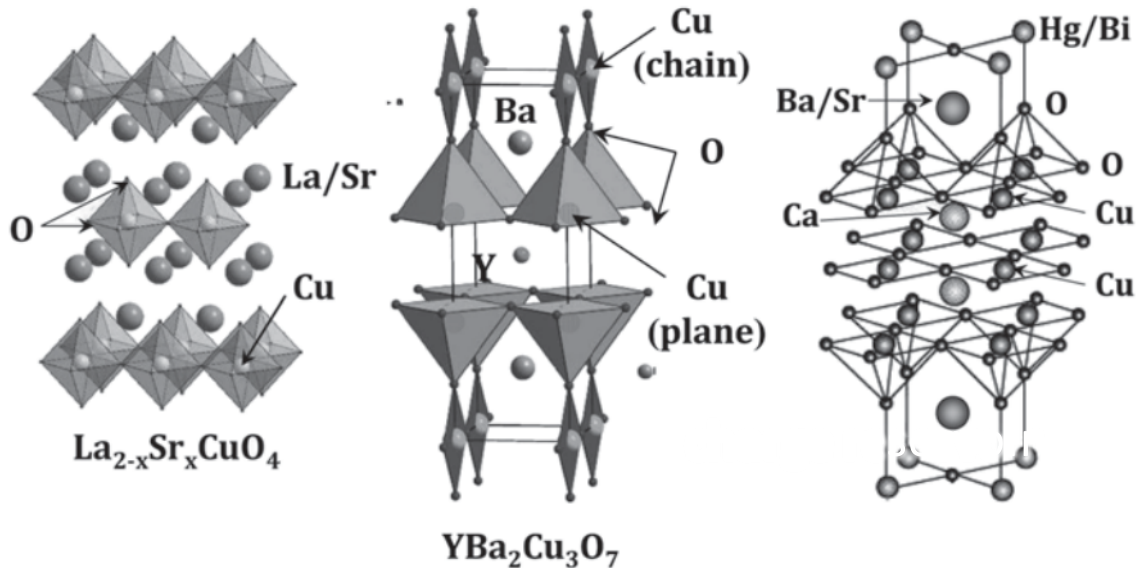
Acknowledgement

- **Fudan STM team: Mingqiang Ren, Yajun Yan, Wei Chen, Chen Chen, Xi Liu, Ran Tao, Tong Zhang**
- **Samples: Xin Yao (for YBCO), Hiroshi Eisaki (for Bi2212 and LSCO) Y. Ando ($\text{Cu}_x\text{Bi}_2\text{Se}_3$)**
- **Discussions:**
 - **Jiangping Hu, Yan Chen, Tao Xiang, Ruihua He, Darren Peets, Yihua Wang**
 - **Guoqing Zheng, Liang Fu**

*Cross-Sectional STM Study of
 $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ and $\text{YBa}_2\text{Cu}_3\text{O}_{7-x}$*

Cuprates

Crystal structure of cuprates



schematic diagram

charge reservoir

CuO_2 layer

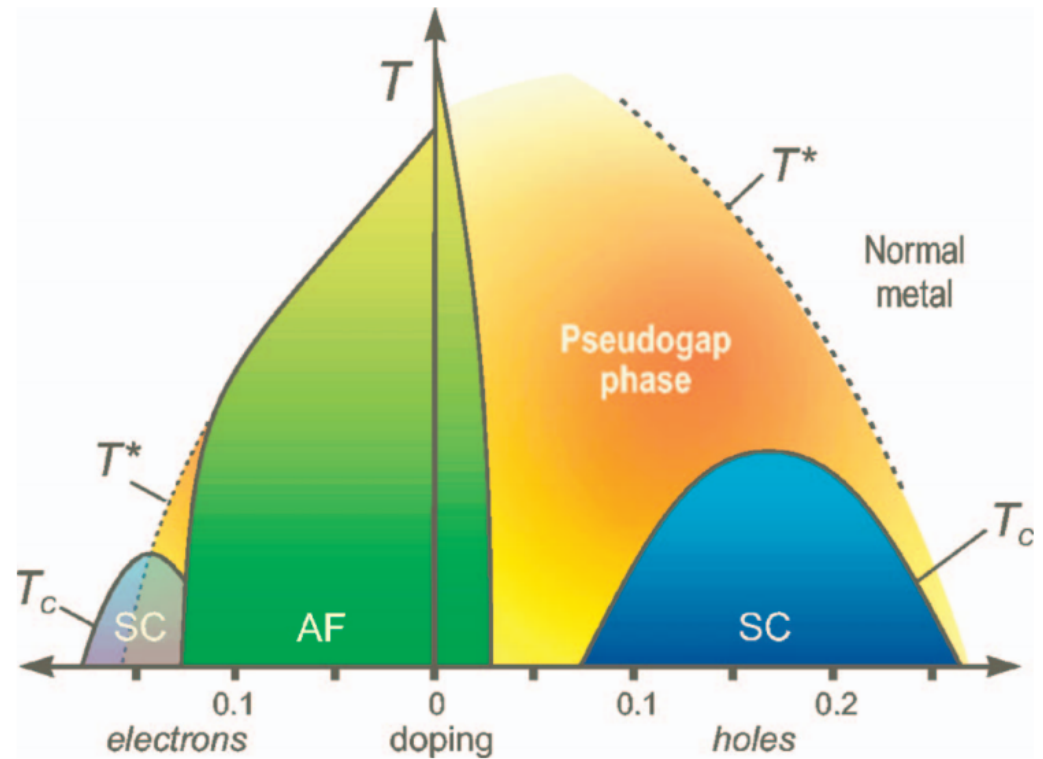
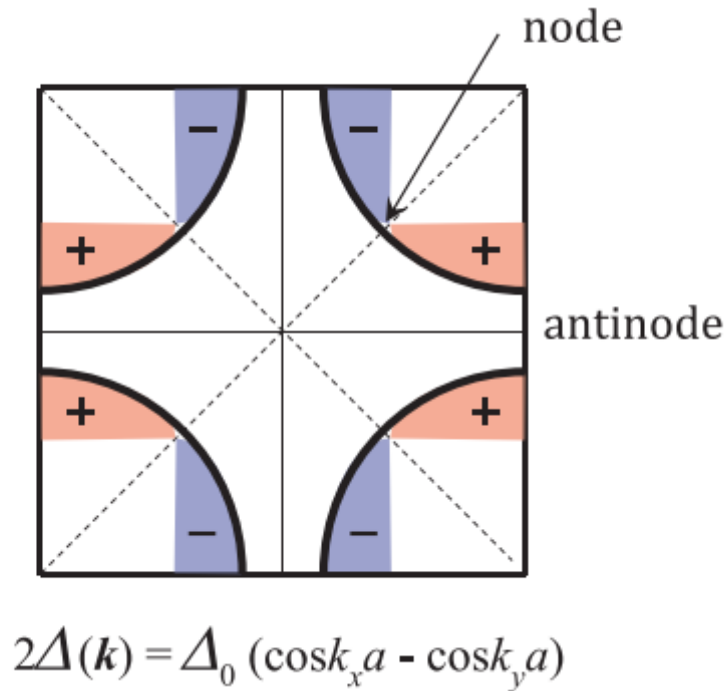
charge reservoir

CuO_2 layer

Uchida S I 2015 High Temperature Superconductivity, the Road to High Critical Temperature (New York: Springer)

We are told: The cuprates are made of conducting CuO_2 layers and insulating charge reservoir oxide layers

d-wave gap and pseudogap



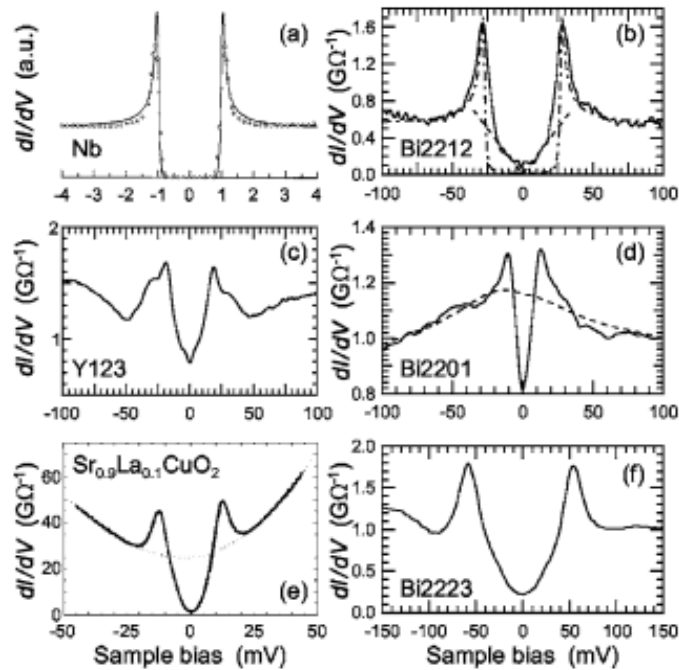
Uchida SI 2015 High Temperature Superconductivity, the Road to High Critical Temperature (New York: Springer)

- the nodal superconducting gap and the pseudogap are critical characteristics of the CuO_2 planes

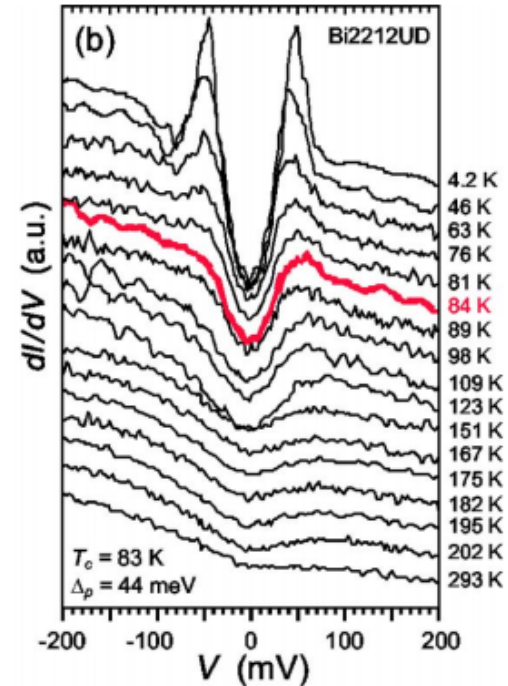
Gap in STS

Spectrum of various cuprates

Optimal doped samples



Under-doped Bi2212

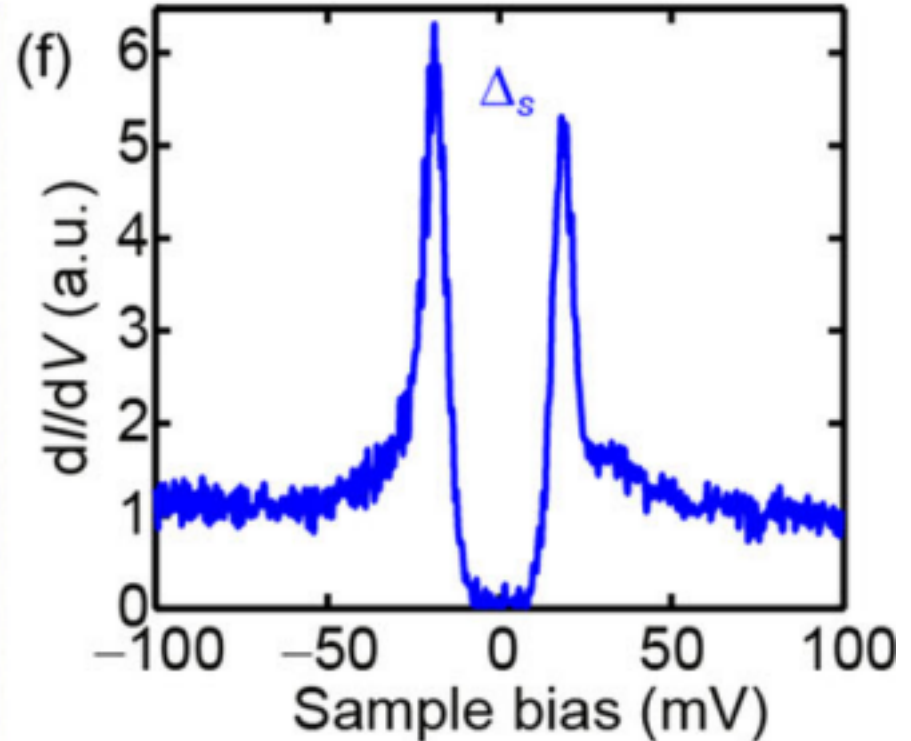
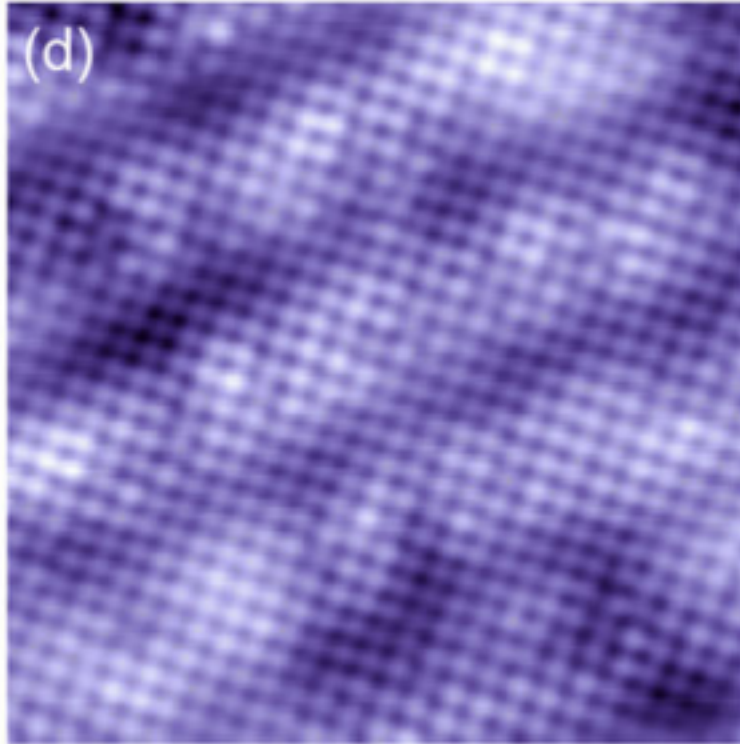


Fischer \emptyset et al 2007 Rev. Mod. Phys. 79 353

- d -wave nodal superconducting gap behaves as a V-shaped gap and the pseudogap appears as a spectral weight suppression over hundreds of meV in STS.

Possible S-wave Pairing ?

CuO₂ monolayer grown on Bi 2212 substrate

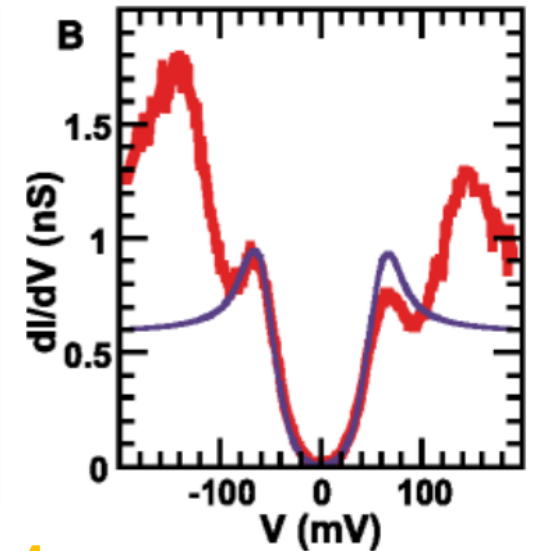
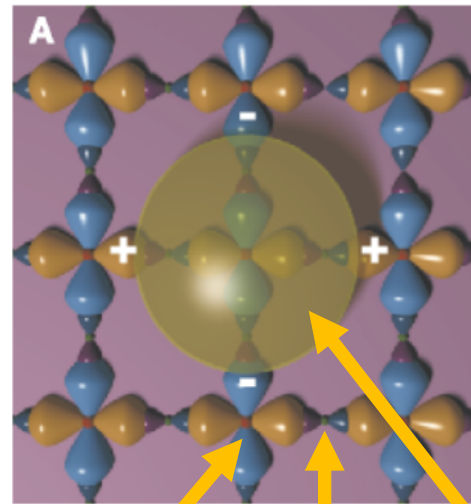
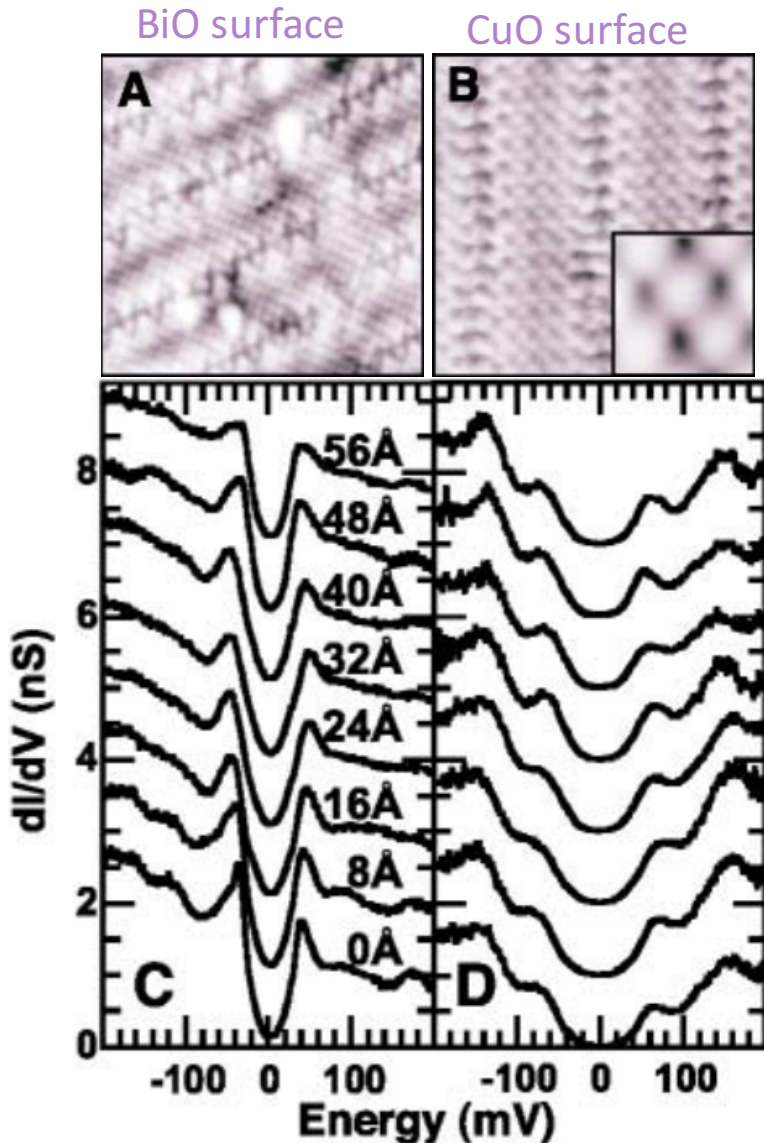


- Pseudogap is inherent to the BiO planes and likely irrelevant to pairing
- CuO₂ films grown on Bi2212 shows a U-shaped gap

The usual STM and ARPES measurements may contain contributions from both the CuO₂ layers and the charge reservoir layers

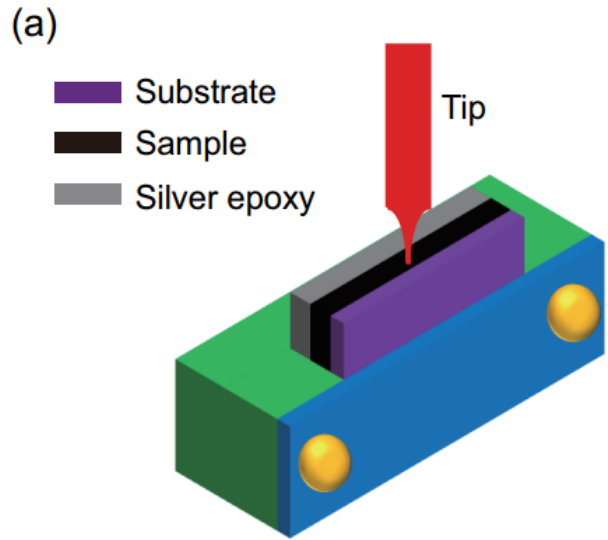
Possible S-wave Pairing ?

Bi2212 thin films (100nm) $T_c = 84$ K
cleaved mechanically at room temperature in vacuum

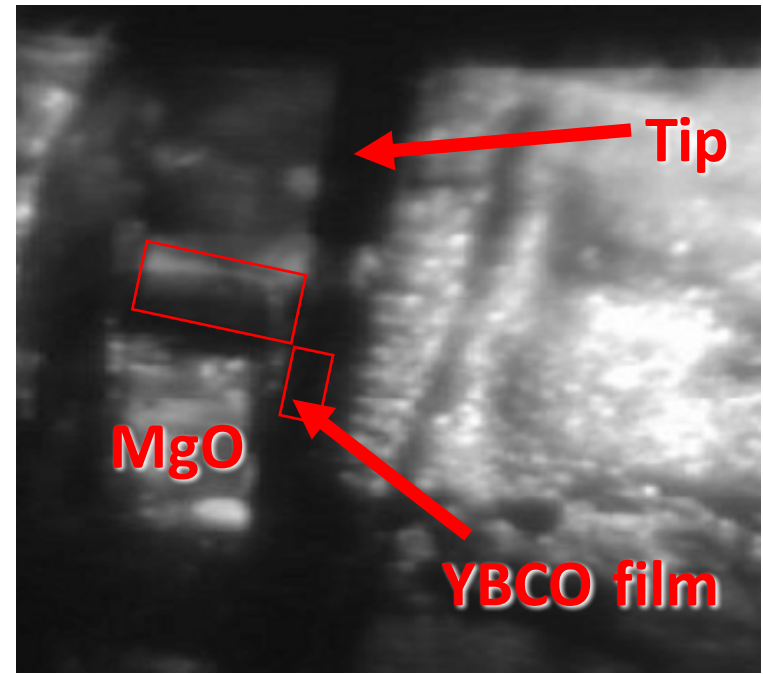


U-gap can be fitted by d-wave pairing considering that the c -axis tunneling is dominated by the $(\pi, 0)$ region.

Experimental Setup



Optical microscope image



Measurement temperature $T = 4.5\text{K}$

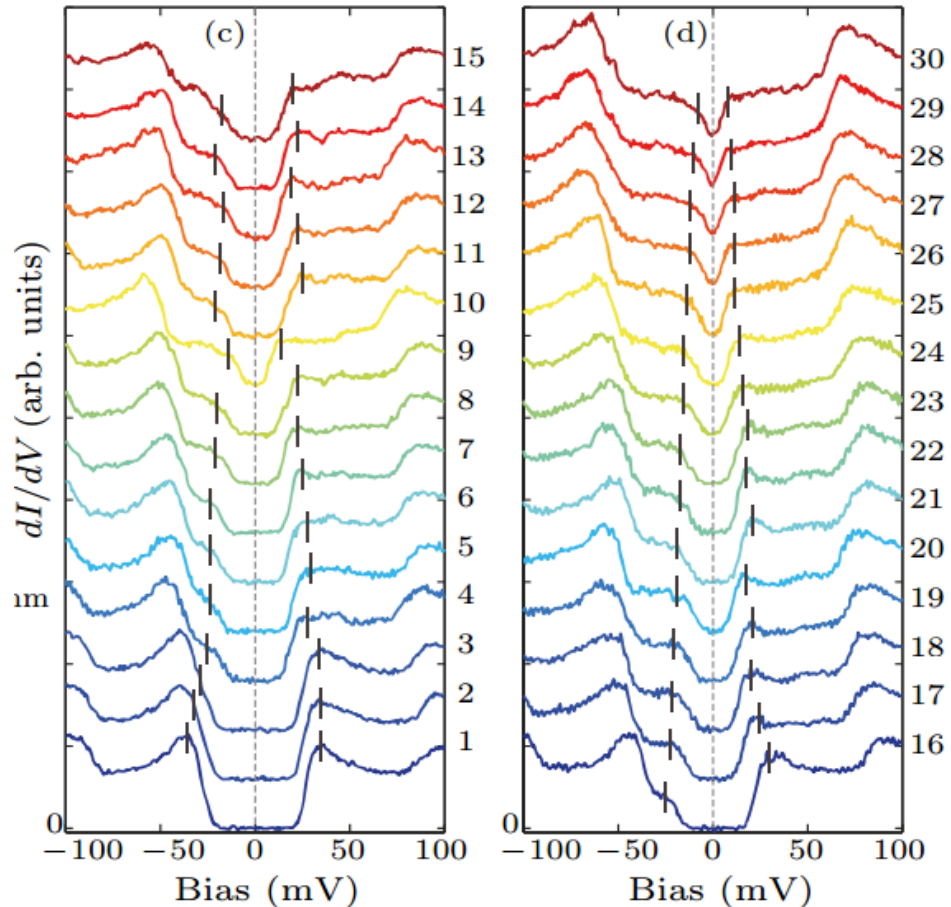
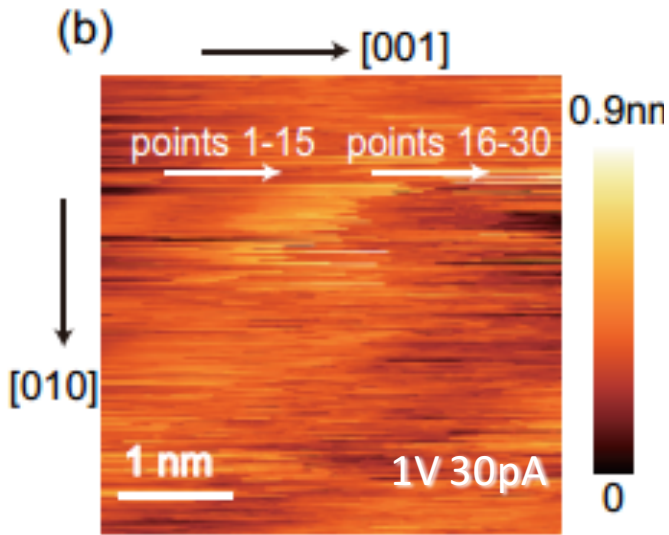
Bi2212: $T_c = 88\text{K}$ YBCO film (600nm thick) : $T_c = 88\text{K}$

Cleavage condition : about 80K in vacuum ($1 \times 10^{-10}\text{mbar}$)

$\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ (100) plane

Bi 2212 single crystal
 $T_c = 88\text{K}$

Cut along (001) Over 1nm



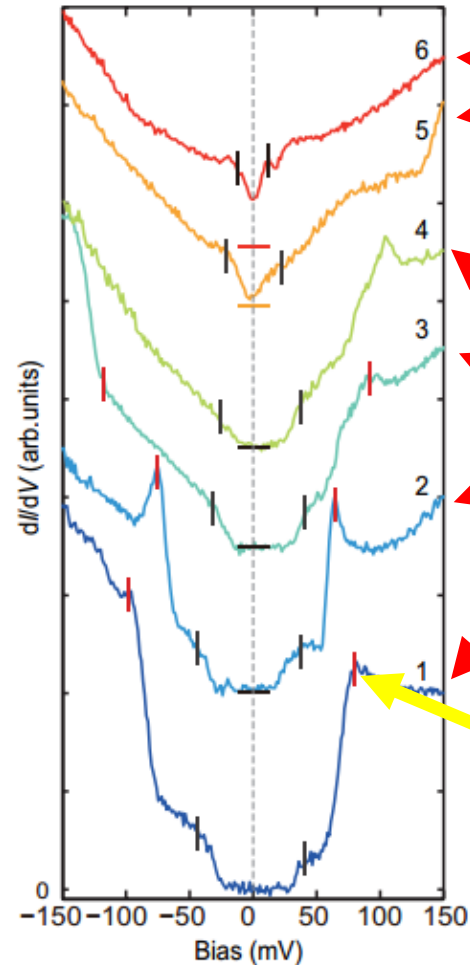
- the overall roughness is less than 1 nm
- Tilt from the (100) plane $< 7^\circ$

- STS shows strong spatial dependence.
- The U-shaped gap gradually become V-shaped within ~ 1 nm

$\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ (100) plane

Bi 2212 single crystal
 $T_c = 88\text{K}$

Representative STS
spectra



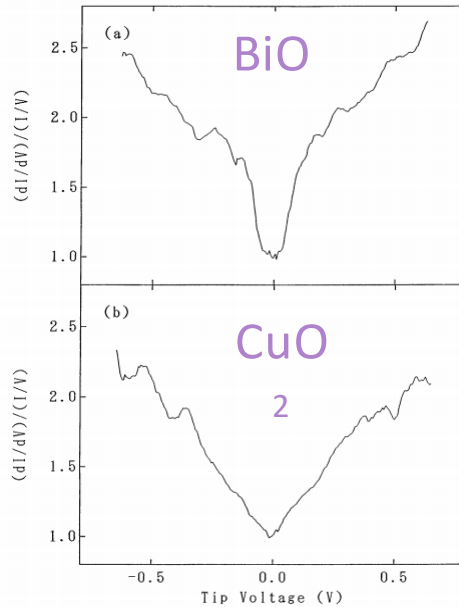
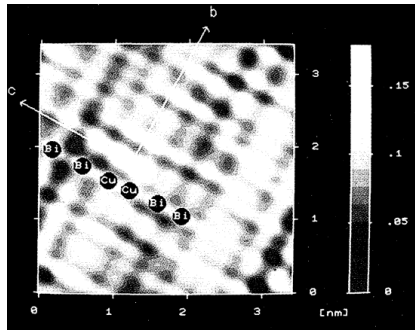
V-shaped gaps
13 - 18 meV

U-shaped gaps
a flat bottom
10 - 25 meV

Larger gap?
60 - 90 meV

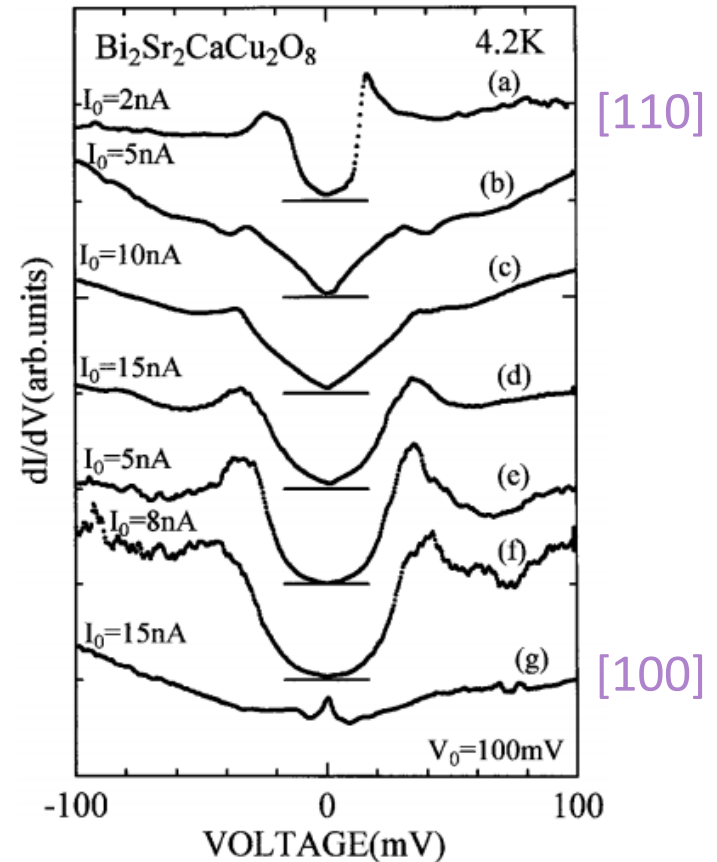
Early Bi2212 data

(100) plane of Bi 2212
prepared with diamond-filing in nitrogen



Hasegawa T, Kitazawa K, 1990 *Jpn. J. Appl. Phys.* 29 L434
Suzuki K et al 1999 *Phys. Rev. Lett.* 83 (3) 616-619

(h,k,0) plane of Bi 2212
prepared with razor blade in air

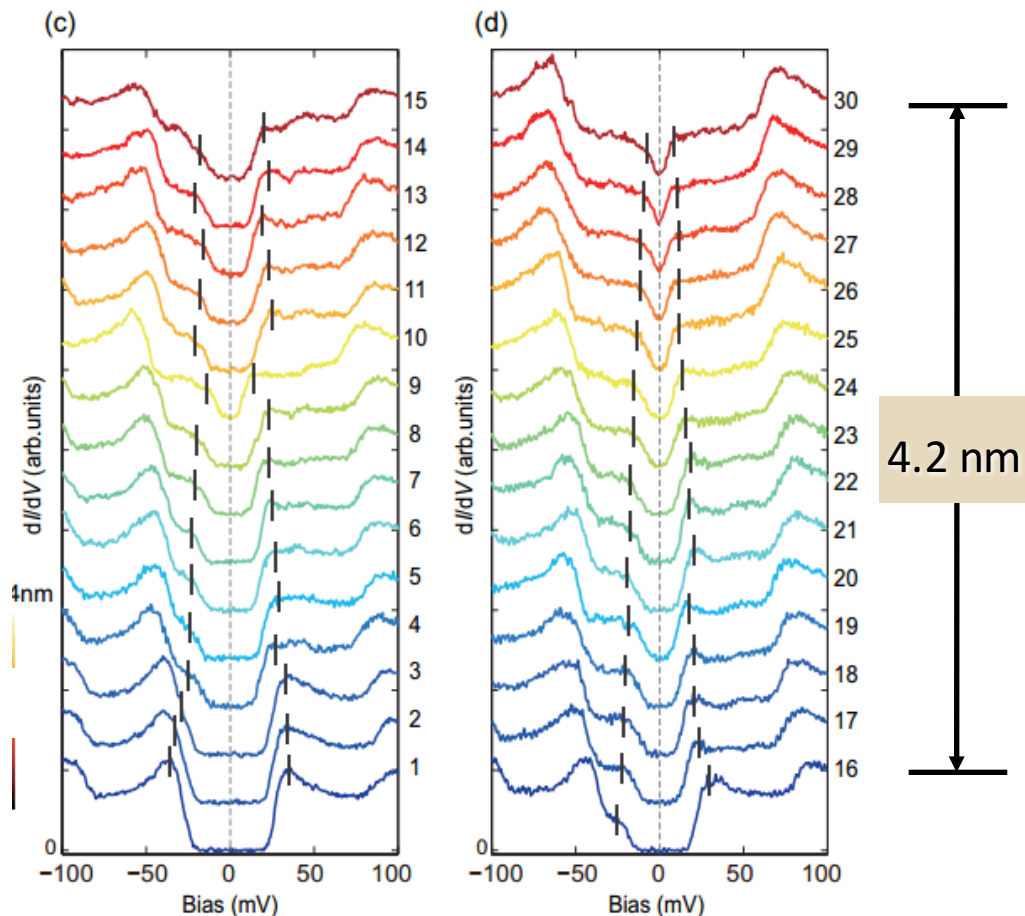
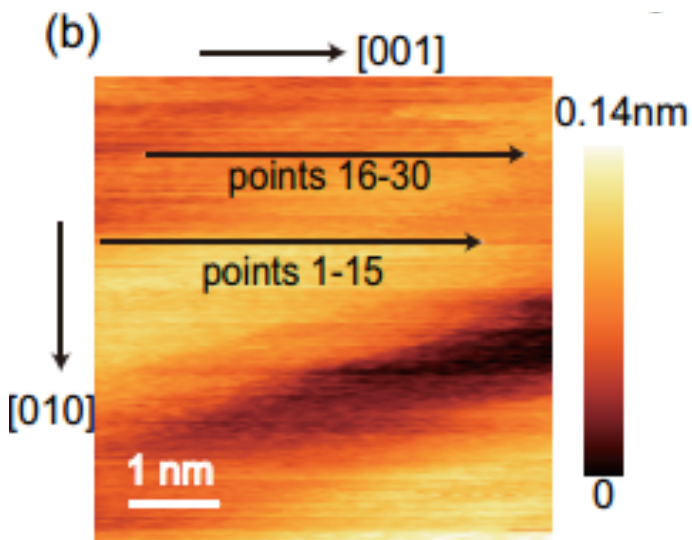


- Previous STM experiments did not observe the U-shaped gap on Bi2212.
- Difference: their samples were prepared outside the vacuum.

YBa₂Cu₃O_{7-x} (100) plane

YBCO thin film grow on MgO
Thickness: 600 nm
T_c = 88K

Cuts along [001] direction
Spatial distance : 0.3 nm



- STS shows strong spatial dependence.
- The U-shaped gap gradually becomes V-shaped.

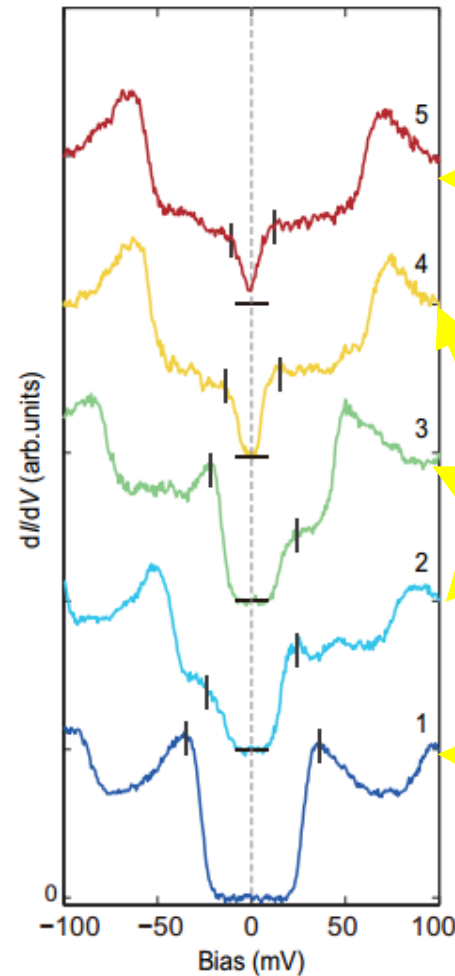
YBa₂Cu₃O_{7-x} (100) plane

YBCO thin film grow on MgO

Thickness: 600 nm

T_c = 88K

Representative STS spectra



V-shaped gap

8 - 10 meV

Smaller U-shaped gap

10 - 35 meV

Well defined U-shaped gap

35 meV

YBa₂Cu₃O_{7-x} (110) plane

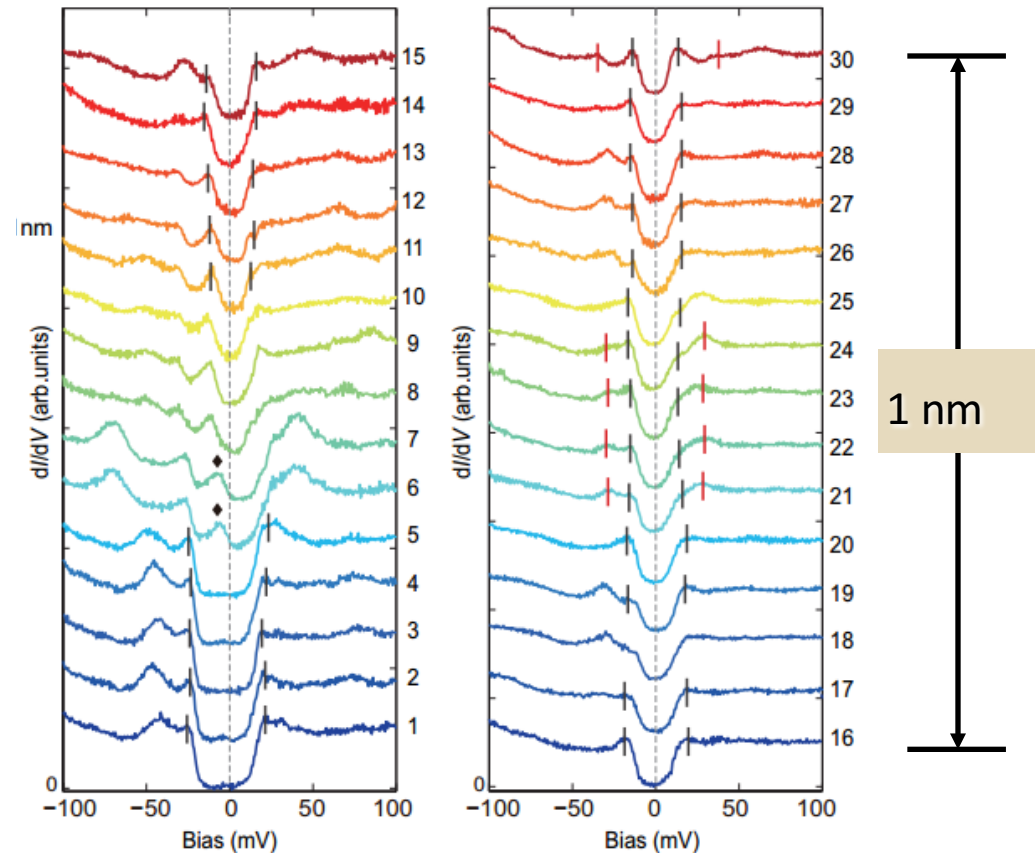
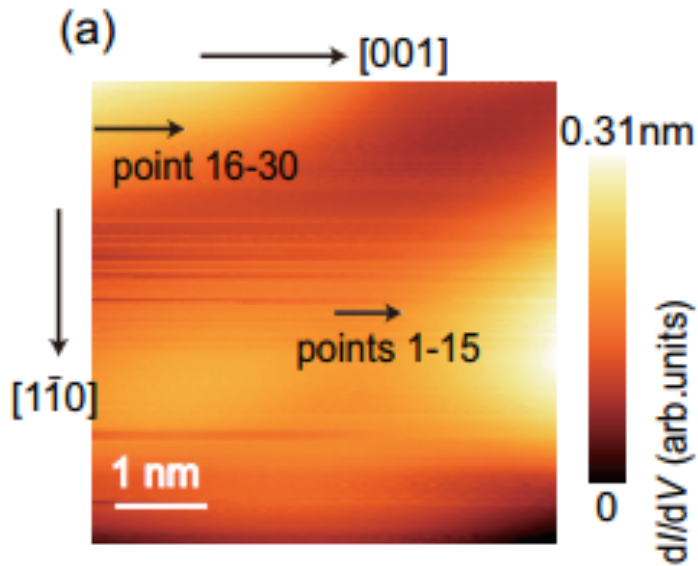
YBCO thin film grow on MgO

Thickness: 600 nm

T_c = 88K

Cuts along [001] direction

Spatial distance : 0.7 Å

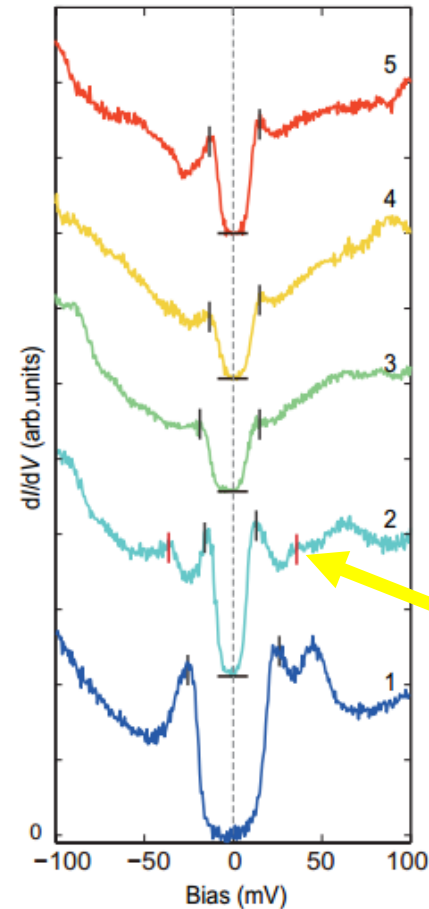


- Well defined U-shaped gap with coherent peaks
- The gap size varies in space
- The maximum gap size on the (110) plane is reduced, compared with that on the (100) plane

YBa₂Cu₃O_{7-x} (110) plane

YBCO thin film grow on MgO
Thickness: 600 nm
T_c = 88K

Representative STS spectra



U-shaped gap

10 - 25 meV

double superconducting gap ?

bosonic modes?

Observations:

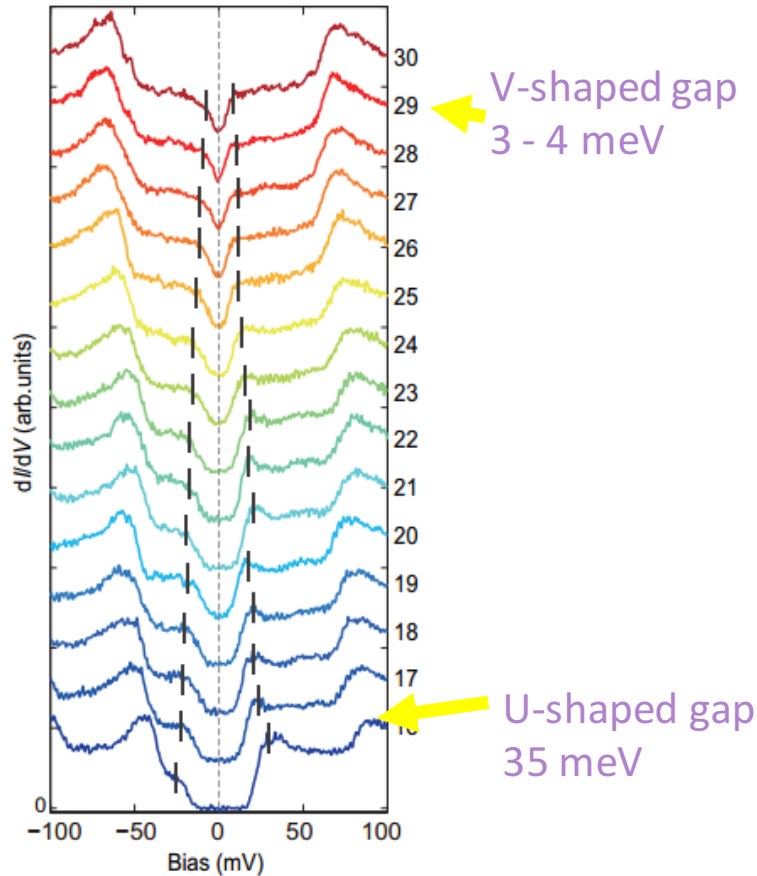
- The low-energy electronic structure of both Bi2212 and YBCO is strongly spatially dependent.
- There are generally two types of gaps: well defined U-shaped gap and small V-shaped gap

Open issues:

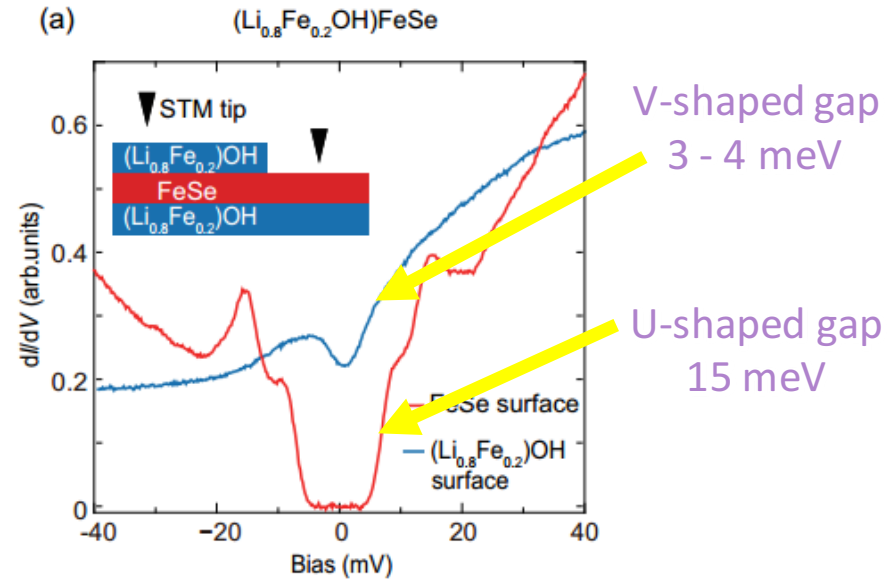
- Need atomically resolved cross-sectional images
- The effects of tunneling matrix elements
- Complexity of polar surface
-

A possibility: proximity effects

From YBCO (100) plane



STS on different layers of $(\text{Li}_{0.8}\text{Fe}_{0.2})\text{OHFeSe}$



Yan Y J et al 2016 Phys. Rev. B 94 134502

- Proximity effect from the superconducting layer (U - shaped gap) to the charge reservoir layers (V - shaped gap)

Simulation of the tunneling matrix element effects

Empirical model based on
WKB approximation

$$\frac{dI}{dV} \propto \int p(\theta) \rho_0(E, \theta) \frac{df(E + eV)}{dV} dE d\theta$$

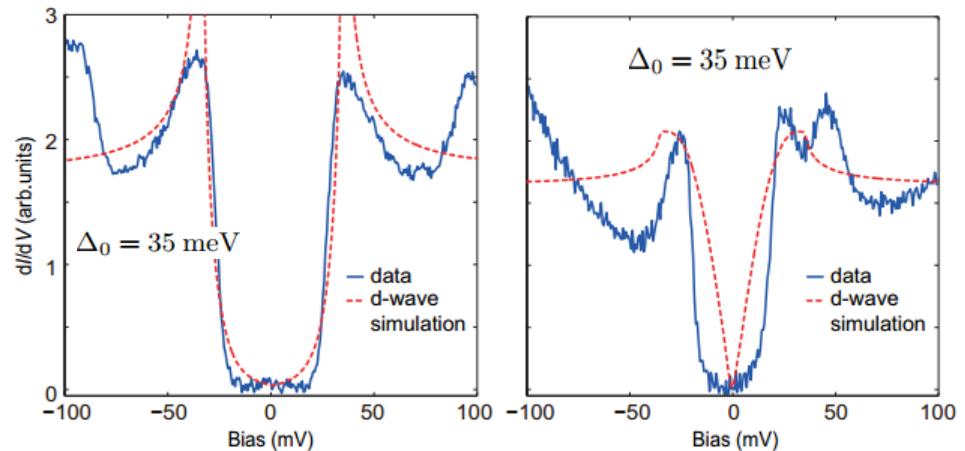
Tunneling probability: $p(\theta) = \exp[-\beta \sin^2(\theta - \theta_0)]$

low energy DOS: $\rho_0(E, \theta) = \text{Re}[E / \sqrt{E^2 - \Delta(\theta)^2}]$

gap
function: $\Delta(\theta) = \Delta_0 \cos(2\theta)$

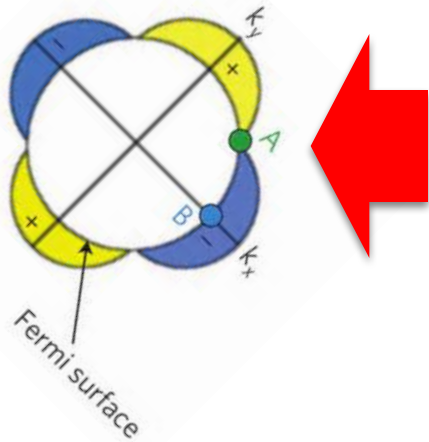
YBCO (100) plane

YBCO (110) plane



Simulations based on a *d*-wave gap cannot readily reproduce the measured U-shaped gap

Lack of zero bias peak

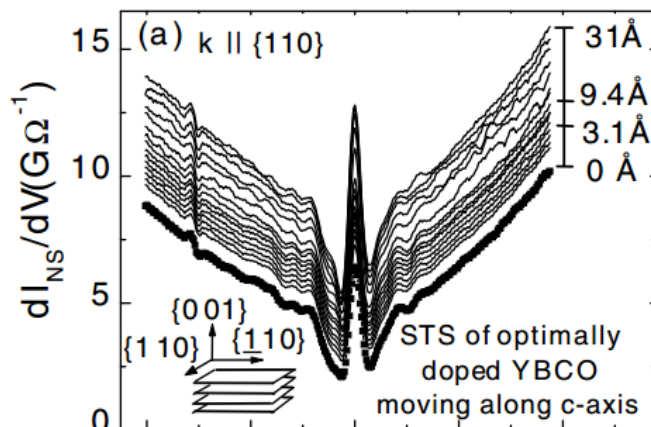


- We did not observe a peak at zero bias on cleaved YBCO along the (110) plane
- Maybe due to the different sample preparation and surface conditions ?

YBCO single crystals with $T_c=91\text{K}$

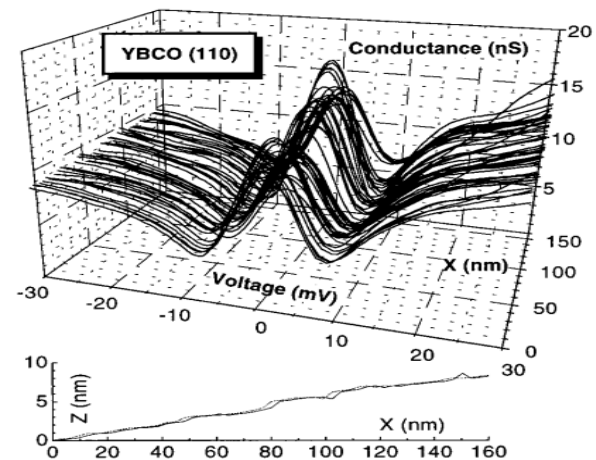
The surface was prepared by chemical etching

Yeh N C et al 2001 Phys. Rev. Lett. 87 087003



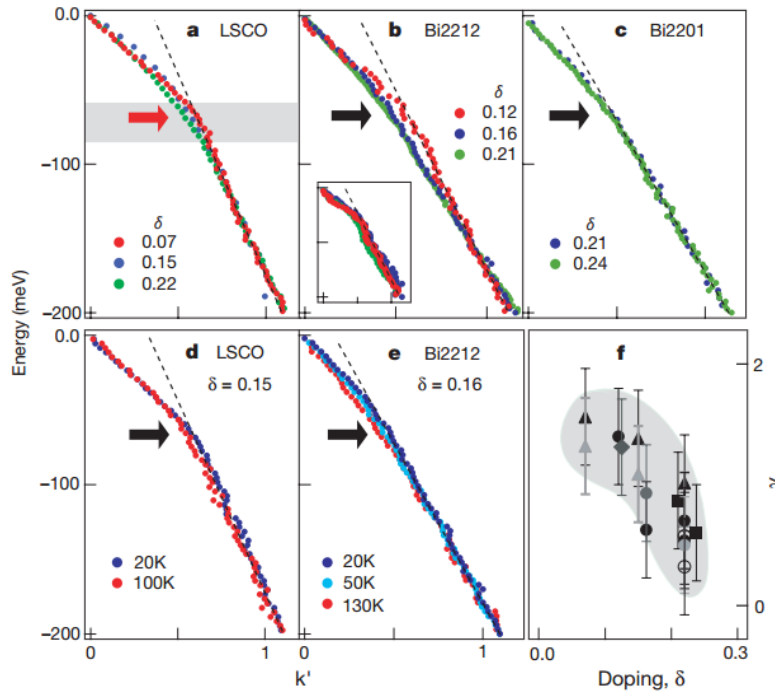
YBCO film (110) plane grown on STO
air-exposure time of about 30 min.

L. Alff et al 1997 Phys. Rev. B 55 R1457



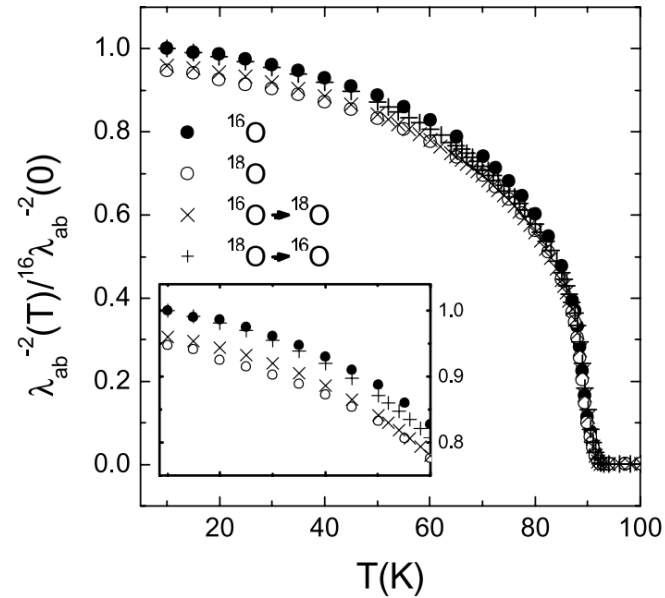
s-wave pairing evidence ?

ARPES study on various cuprates



Lanzara A et al 2001 Nature 412 510

muon-spin rotation study on the nearly optimally doped YBCO



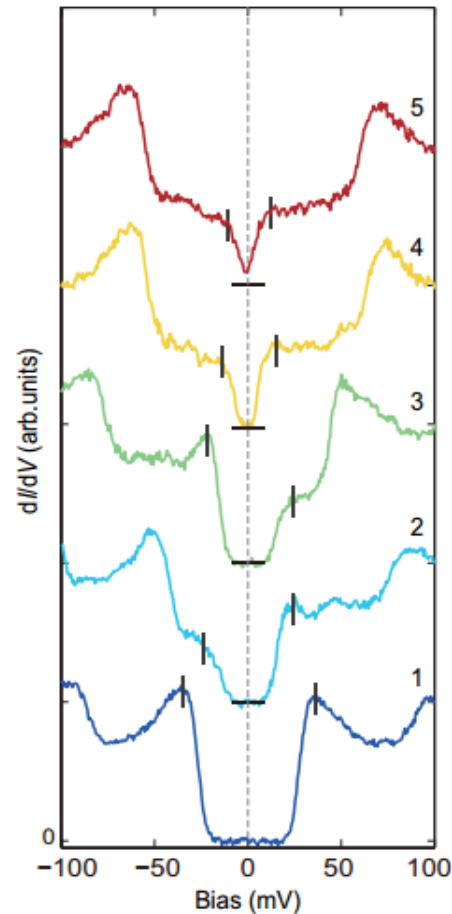
Khasanov R et al 2004 Phys. Rev. Lett. 92 057602

- electron phonon coupling signature in ARPES.
- Isotope effects of the superfluid density

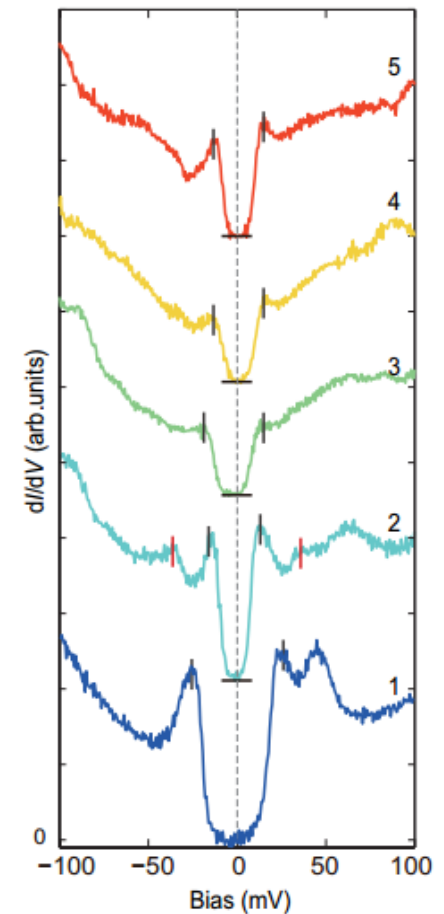
Summary

- Electronic states of Bi2212 and YBCO have strong spatial dependence along c .
- U - shaped gap on both YBCO(100) and YBCO (110) plane
- U - shaped gap could not easily understood based on d - wave pairing
- V shaped gap maybe in the charge reservoir layers, whose role needs to be checked further.
- There is a long list of experiment supporting d-wave, our findings need further investigations.

YBCO (100) plane



YBCO (110) plane



*Nematic (2-fold symmetric) field dependence of
the superconducting gap of $\text{Cu}_x\text{Bi}_2\text{Se}_3$*



Ya-Jun Yan

Thank you